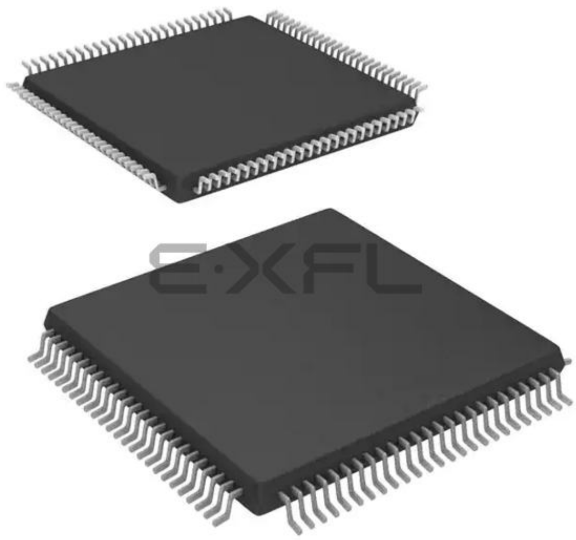


Welcome to E-XFL.COM

Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	4
Number of Macrocells	64
Number of Gates	1250
Number of I/O	66
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epm3064atc100-7n

…and More Features

- PCI compatible
- Bus–friendly architecture including programmable slew–rate control
- Open–drain output option
- Programmable macrocell flipflops with individual clear, preset, clock, and clock enable controls
- Programmable power–saving mode for a power reduction of over 50% in each macrocell
- Configurable expander product–term distribution, allowing up to 32 product terms per macrocell
- Programmable security bit for protection of proprietary designs
- Enhanced architectural features, including:
  - 6 or 10 pin– or logic–driven output enable signals
  - Two global clock signals with optional inversion
  - Enhanced interconnect resources for improved routability
  - Programmable output slew–rate control
- Software design support and automatic place–and–route provided by Altera's development systems for Windows–based PCs and Sun SPARCstations, and HP 9000 Series 700/800 workstations
- Additional design entry and simulation support provided by EDIF 2 0 0 and 3 0 0 netlist files, library of parameterized modules (LPM), Verilog HDL, VHDL, and other interfaces to popular EDA tools from third–party manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplicity, and VeriBest
- Programming support with the Altera master programming unit (MPU), MasterBlaster™ communications cable, ByteBlasterMV™ parallel port download cable, BitBlaster™ serial download cable as well as programming hardware from third–party manufacturers and any in–circuit tester that supports Jam™ Standard Test and Programming Language (STAPL) Files (**.jam**), Jam STAPL Byte-Code Files (**.jbc**), or Serial Vector Format Files (**.svf**)

General Description

MAX 3000A devices are low–cost, high–performance devices based on the Altera MAX architecture. Fabricated with advanced CMOS technology, the EEPROM–based MAX 3000A devices operate with a 3.3-V supply voltage and provide 600 to 10,000 usable gates, ISP, pin-to-pin delays as fast as 4.5 ns, and counter speeds of up to 227.3 MHz. MAX 3000A devices in the –4, –5, –6, –7, and –10 speed grades are compatible with the timing requirements of the PCI Special Interest Group (PCI SIG) ***PCI Local Bus Specification, Revision 2.2***. See Table 2.

For registered functions, each macrocell flipflop can be individually programmed to implement D, T, JK, or SR operation with programmable clock control. The flipflop can be bypassed for combinatorial operation. During design entry, the designer specifies the desired flipflop type; the Altera development system software then selects the most efficient flipflop operation for each registered function to optimize resource utilization.

Each programmable register can be clocked in three different modes:

- Global clock signal mode, which achieves the fastest clock–to–output performance.
- Global clock signal enabled by an active–high clock enable. A clock enable is generated by a product term. This mode provides an enable on each flipflop while still achieving the fast clock–to–output performance of the global clock.
- Array clock implemented with a product term. In this mode, the flipflop can be clocked by signals from buried macrocells or I/O pins.

Two global clock signals are available in MAX 3000A devices. As shown in Figure 1, these global clock signals can be the true or the complement of either of the two global clock pins, `GCLK1` or `GCLK2`.

Each register also supports asynchronous preset and clear functions. As shown in Figure 2, the product–term select matrix allocates product terms to control these operations. Although the product–term–driven preset and clear from the register are active high, active–low control can be obtained by inverting the signal within the logic array. In addition, each register clear function can be individually driven by the active–low dedicated global clear pin (`GCLRn`).

All registers are cleared upon power-up. By default, all registered outputs drive low when the device is powered up. You can set the registered outputs to drive high upon power-up through the Quartus® II software. Quartus II software uses the NOT Gate Push-Back method, which uses an additional macrocell to set the output high. To set this in the Quartus II software, go to the Assignment Editor and set the **Power-Up Level** assignment for the register to **High**.

Expander Product Terms

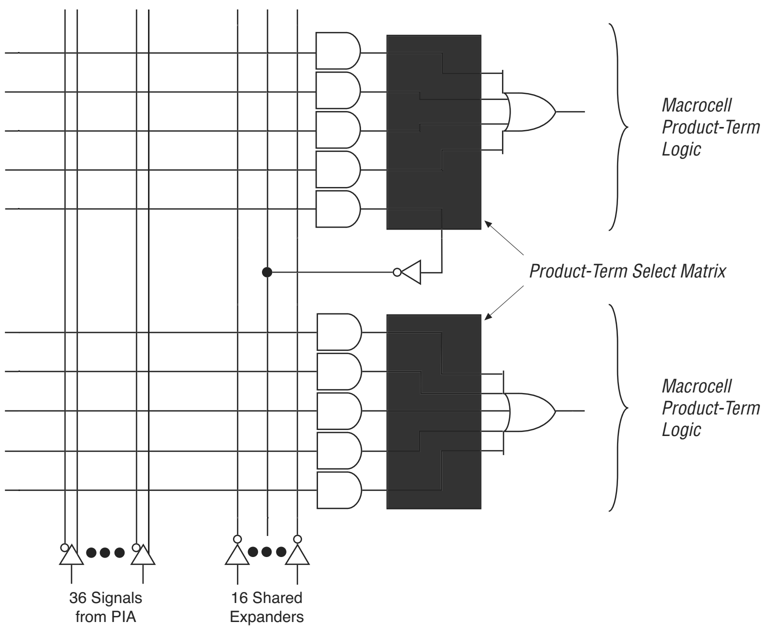
Although most logic functions can be implemented with the five product terms available in each macrocell, highly complex logic functions require additional product terms. Another macrocell can be used to supply the required logic resources. However, the MAX 3000A architecture also offers both shareable and parallel expander product terms (“expanders”) that provide additional product terms directly to any macrocell in the same LAB. These expanders help ensure that logic is synthesized with the fewest possible logic resources to obtain the fastest possible speed.

Shareable Expanders

Each LAB has 16 shareable expanders that can be viewed as a pool of uncommitted single product terms (one from each macrocell) with inverted outputs that feed back into the logic array. Each shareable expander can be used and shared by any or all macrocells in the LAB to build complex logic functions. Shareable expanders incur a small delay (t_{SEXP}). Figure 3 shows how shareable expanders can feed multiple macrocells.

Figure 3. MAX 3000A Shareable Expanders

Shareable expanders can be shared by any or all macrocells in an LAB.



By combining the pulse and shift times for each of the programming stages, the program or verify time can be derived as a function of the TCK frequency, the number of devices, and specific target device(s). Because different ISP-capable devices have a different number of EEPROM cells, both the total fixed and total variable times are unique for a single device.

Programming a Single MAX 3000A Device

The time required to program a single MAX 3000A device in-system can be calculated from the following formula:

$$t_{PROG} = t_{PPULSE} + \frac{Cycle_{PTCK}}{f_{TCK}}$$

where: t_{PROG} = Programming time
t_{PPULSE} = Sum of the fixed times to erase, program, and verify the EEPROM cells
$Cycle_{PTCK}$ = Number of TCK cycles to program a device
f_{TCK} = TCK frequency

The ISP times for a stand-alone verification of a single MAX 3000A device can be calculated from the following formula:

$$t_{VER} = t_{VPULSE} + \frac{Cycle_{VTCK}}{f_{TCK}}$$

where: t_{VER} = Verify time
t_{VPULSE} = Sum of the fixed times to verify the EEPROM cells
$Cycle_{VTCK}$ = Number of TCK cycles to verify a device

The programming times described in Tables 4 through 6 are associated with the worst-case method using the enhanced ISP algorithm.

Table 4. MAX 3000A t_{PULSE} & $Cycle_{TCK}$ Values

Device	Programming		Stand-Alone Verification	
	t_{PPULSE} (s)	$Cycle_{PTCK}$	t_{VPULSE} (s)	$Cycle_{VTCK}$
EPM3032A	2.00	55,000	0.002	18,000
EPM3064A	2.00	105,000	0.002	35,000
EPM3128A	2.00	205,000	0.002	68,000
EPM3256A	2.00	447,000	0.002	149,000
EPM3512A	2.00	890,000	0.002	297,000

Tables 5 and 6 show the in-system programming and stand alone verification times for several common test clock frequencies.

Table 5. MAX 3000A In-System Programming Times for Different Test Clock Frequencies

Device	f_{TCK}								Units
	10 MHz	5 MHz	2 MHz	1 MHz	500 kHz	200 kHz	100 kHz	50 kHz	
EPM3032A	2.01	2.01	2.03	2.06	2.11	2.28	2.55	3.10	s
EPM3064A	2.01	2.02	2.05	2.11	2.21	2.53	3.05	4.10	s
EPM3128A	2.02	2.04	2.10	2.21	2.41	3.03	4.05	6.10	s
EPM3256A	2.05	2.09	2.23	2.45	2.90	4.24	6.47	10.94	s
EPM3512A	2.09	2.18	2.45	2.89	3.78	6.45	10.90	19.80	s

Table 6. MAX 3000A Stand-Alone Verification Times for Different Test Clock Frequencies

Device	f_{TCK}								Units
	10 MHz	5 MHz	2 MHz	1 MHz	500 kHz	200 kHz	100 kHz	50 kHz	
EPM3032A	0.00	0.01	0.01	0.02	0.04	0.09	0.18	0.36	s
EPM3064A	0.01	0.01	0.02	0.04	0.07	0.18	0.35	0.70	s
EPM3128A	0.01	0.02	0.04	0.07	0.14	0.34	0.68	1.36	s
EPM3256A	0.02	0.03	0.08	0.15	0.30	0.75	1.49	2.98	s
EPM3512A	0.03	0.06	0.15	0.30	0.60	1.49	2.97	5.94	s

The instruction register length of MAX 3000A devices is 10 bits. The IDCODE and USERCODE register length is 32 bits. Tables 8 and 9 show the boundary–scan register length and device IDCODE information for MAX 3000A devices.

Table 8. MAX 3000A Boundary–Scan Register Length

Device	Boundary–Scan Register Length
EPM3032A	96
EPM3064A	192
EPM3128A	288
EPM3256A	480
EPM3512A	624

Table 9. 32–Bit MAX 3000A Device IDCODE Value *Note (1)*

Device	IDCODE (32 bits)			
	Version (4 Bits)	Part Number (16 Bits)	Manufacturer's Identity (11 Bits)	1 (1 Bit) *(2)*
EPM3032A	0001	0111 0000 0011 0010	00001101110	1
EPM3064A	0001	0111 0000 0110 0100	00001101110	1
EPM3128A	0001	0111 0001 0010 1000	00001101110	1
EPM3256A	0001	0111 0010 0101 0110	00001101110	1
EPM3512A	0001	0111 0101 0001 0010	00001101110	1

Notes:
(1) The most significant bit (MSB) is on the left.
(2) The least significant bit (LSB) for all JTAG IDCODEs is 1.

See *Application Note 39 (IEEE 1149.1 (JTAG) Boundary–Scan Testing in Altera Devices)* for more information on JTAG BST.

Figure 7 shows the timing information for the JTAG signals.

Figure 7. MAX 3000A JTAG Waveforms

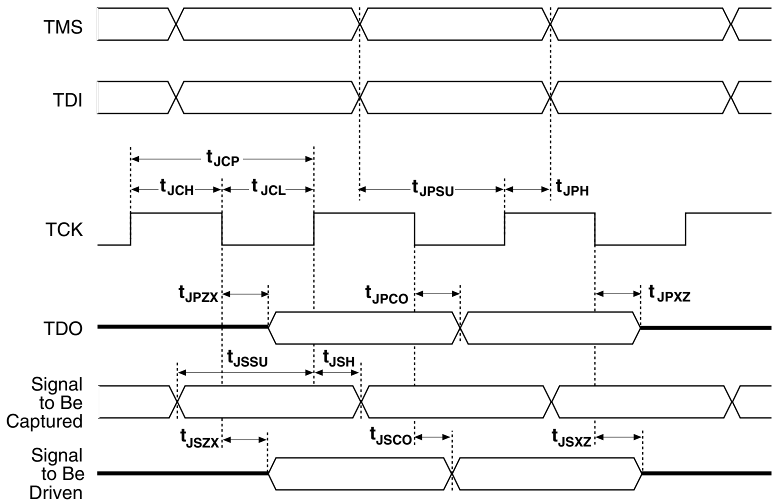


Table 10 shows the JTAG timing parameters and values for MAX 3000A devices.

Table 10. JTAG Timing Parameters & Values for MAX 3000A Devices

Symbol	Parameter	Min	Max	Unit
t_{JCP}	`TCK` clock period	100		ns
t_{JCH}	`TCK` clock high time	50		ns
t_{JCL}	`TCK` clock low time	50		ns
t_{JPSU}	JTAG port setup time	20		ns
t_{JPH}	JTAG port hold time	45		ns
t_{JPCO}	JTAG port clock to output		25	ns
t_{JPZX}	JTAG port high impedance to valid output		25	ns
t_{JPXZ}	JTAG port valid output to high impedance		25	ns
t_{JSSU}	Capture register setup time	20		ns
t_{JSH}	Capture register hold time	45		ns
t_{JSCO}	Update register clock to output		25	ns
t_{JSZX}	Update register high impedance to valid output		25	ns
t_{JSXZ}	Update register valid output to high impedance		25	ns

Open–Drain Output Option

MAX 3000A devices provide an optional open–drain (equivalent to open-collector) output for each I/O pin. This open–drain output enables the device to provide system–level control signals (e.g., interrupt and write enable signals) that can be asserted by any of several devices. It can also provide an additional wired–OR plane.

Open-drain output pins on MAX 3000A devices (with a pull-up resistor to the 5.0-V supply) can drive 5.0-V CMOS input pins that require a high V_{IH}. When the open-drain pin is active, it will drive low. When the pin is inactive, the resistor will pull up the trace to 5.0 V, thereby meeting CMOS requirements. The open-drain pin will only drive low or tri-state; it will never drive high. The rise time is dependent on the value of the pull-up resistor and load impedance. The I_{OL} current specification should be considered when selecting a pull-up resistor

Slew–Rate Control

The output buffer for each MAX 3000A I/O pin has an adjustable output slew rate that can be configured for low–noise or high–speed performance. A faster slew rate provides high–speed transitions for high-performance systems. However, these fast transitions may introduce noise transients into the system. A slow slew rate reduces system noise, but adds a nominal delay of 4 to 5 ns. When the configuration cell is turned off, the slew rate is set for low–noise performance. Each I/O pin has an individual EEPROM bit that controls the slew rate, allowing designers to specify the slew rate on a pin–by–pin basis. The slew rate control affects both the rising and falling edges of the output signal.

Design Security

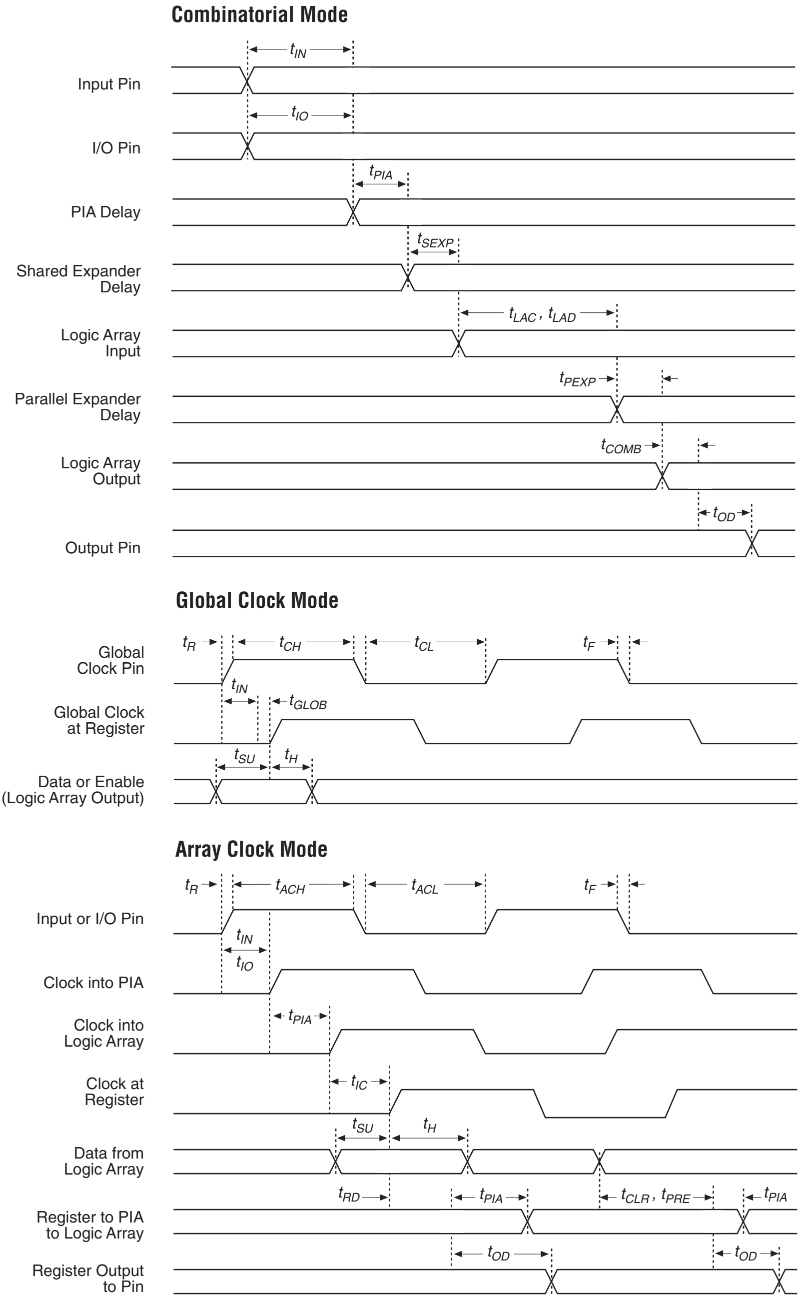
All MAX 3000A devices contain a programmable security bit that controls access to the data programmed into the device. When this bit is programmed, a design implemented in the device cannot be copied or retrieved. This feature provides a high level of design security because programmed data within EEPROM cells is invisible. The security bit that controls this function, as well as all other programmed data, is reset only when the device is reprogrammed.

Generic Testing

MAX 3000A devices are fully tested. Complete testing of each programmable EEPROM bit and all internal logic elements ensures 100% programming yield. AC test measurements are taken under conditions equivalent to those shown in Figure 8. Test patterns can be used and then erased during early stages of the production flow.

Figure 11. MAX 3000A Switching Waveforms

t_R & t_F < 2 ns. Inputs are driven at 3 V for a logic high and 0 V for a logic low. All timing characteristics are measured at 1.5 V.



Tables 16 through 23 show EPM3032A, EPM3064A, EPM3128A, EPM3256A, and EPM3512A timing information.

Table 16. EPM3032A External Timing Parameters *Note (1)*									
Symbol	**Parameter**	**Conditions**	**Speed Grade**						**Unit**
			–4		**–7**		**–10**		
			Min	**Max**	**Min**	**Max**	**Min**	**Max**	
t_{PD1}	Input to non–registered output	C1 = 35 pF *(2)*		4.5		7.5		10	ns
t_{PD2}	I/O input to non–registered output	C1 = 35 pF *(2)*		4.5		7.5		10	ns
t_{SU}	Global clock setup time	*(2)*	2.9		4.7		6.3		ns
t_{H}	Global clock hold time	*(2)*	0.0		0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.0	1.0	5.0	1.0	6.7	ns
t_{CH}	Global clock high time		2.0		3.0		4.0		ns
t_{CL}	Global clock low time		2.0		3.0		4.0		ns
t_{ASU}	Array clock setup time	*(2)*	1.6		2.5		3.6		ns
t_{AH}	Array clock hold time	*(2)*	0.3		0.5		0.5		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	4.3	1.0	7.2	1.0	9.4	ns
t_{ACH}	Array clock high time		2.0		3.0		4.0		ns
t_{ACL}	Array clock low time		2.0		3.0		4.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	2.0		3.0		4.0		ns
t_{CNT}	Minimum global clock period	*(2)*		4.4		7.2		9.7	ns
f_{CNT}	Maximum internal global clock frequency	*(2)*, *(4)*	227.3		138.9		103.1		MHz
t_{ACNT}	Minimum array clock period	*(2)*		4.4		7.2		9.7	ns
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	227.3		138.9		103.1		MHz

Table 19. EPM3064A Internal Timing Parameters (Part 1 of 2) Note (1)									
Symbol	Parameter	Conditions	Speed Grade						Unit
			–4		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.6		1.1		1.4	ns
t_{IO}	I/O input pad and buffer delay			0.6		1.1		1.4	ns
t_{SEXP}	Shared expander delay			1.8		3.0		3.9	ns
t_{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.5		2.5		3.2	ns
t_{LAC}	Logic control array delay			0.6		1.0		1.2	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.3		1.8	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.8		2.3	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.3		6.8	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		4.5		4.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t_{SU}	Register setup time		1.3		2.0		2.9		ns
t_{H}	Register hold time		0.6		1.0		1.3		ns
t_{RD}	Register delay			0.7		1.2		1.6	ns
t_{COMB}	Combinatorial delay			0.6		0.9		1.3	ns
t_{IC}	Array clock delay			1.2		1.9		2.5	ns
t_{EN}	Register enable time			0.6		1.0		1.2	ns
t_{GLOB}	Global control delay			1.0		1.5		2.2	ns
t_{PRE}	Register preset time			1.3		2.1		2.9	ns

Table 20. EPM3128A External Timing Parameters *Note (1)*									
Symbol	**Parameter**	**Conditions**	**Speed Grade**						**Unit**
			–5		**–7**		**–10**		
			Min	**Max**	**Min**	**Max**	**Min**	**Max**	
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	192.3		129.9		98.0		MHz

Table 21. EPM3128A Internal Timing Parameters (Part 1 of 2) *Note (1)*									
Symbol	**Parameter**	**Conditions**	**Speed Grade**						**Unit**
			–5		**–7**		**–10**		
			Min	**Max**	**Min**	**Max**	**Min**	**Max**	
t_{IN}	Input pad and buffer delay			0.7		1.0		1.4	ns
t_{IO}	I/O input pad and buffer delay			0.7		1.0		1.4	ns
t_{SEXP}	Shared expander delay			2.0		2.9		3.8	ns
t_{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.6		2.4		3.1	ns
t_{LAC}	Logic control array delay			0.7		1.0		1.3	ns
t_{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.2		1.6	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.7		2.1	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.2		6.6	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		4.5		4.5		5.5	ns
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns

Table 21. EPM3128A Internal Timing Parameters (Part 2 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			–5		–7		–10		
			Min	Max	Min	Max	Min	Max	
t_{SU}	Register setup time		1.4		2.1		2.9		ns
t_{H}	Register hold time		0.6		1.0		1.3		ns
t_{RD}	Register delay			0.8		1.2		1.6	ns
t_{COMB}	Combinatorial delay			0.5		0.9		1.3	ns
t_{IC}	Array clock delay			1.2		1.7		2.2	ns
t_{EN}	Register enable time			0.7		1.0		1.3	ns
t_{GLOB}	Global control delay			1.1		1.6		2.0	ns
t_{PRE}	Register preset time			1.4		2.0		2.7	ns
t_{CLR}	Register clear time			1.4		2.0		2.7	ns
t_{PIA}	PIA delay	*(2)*		1.4		2.0		2.6	ns
t_{LPA}	Low–power adder	*(5)*		4.0		4.0		5.0	ns

Table 22. EPM3256A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade				Unit
			–7		–10		
			Min	Max	Min	Max	
t_{PD1}	Input to non–registered output	C1 = 35 pF *(2)*		7.5		10	ns
t_{PD2}	I/O input to non–registered output	C1 = 35 pF *(2)*		7.5		10	ns
t_{SU}	Global clock setup time	*(2)*	5.2		6.9		ns
t_{H}	Global clock hold time	*(2)*	0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.8	1.0	6.4	ns
t_{CH}	Global clock high time		3.0		4.0		ns
t_{CL}	Global clock low time		3.0		4.0		ns
t_{ASU}	Array clock setup time	*(2)*	2.7		3.6		ns
t_{AH}	Array clock hold time	*(2)*	0.3		0.5		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	7.3	1.0	9.7	ns
t_{ACH}	Array clock high time		3.0		4.0		ns
t_{ACL}	Array clock low time		3.0		4.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	3.0		4.0		ns

Table 22. EPM3256A External Timing Parameters *Note (1)*							
Symbol	Parameter	Conditions	Speed Grade				Unit
			–7		–10		
			Min	Max	Min	Max	
t_{CNT}	Minimum global clock period	*(2)*		7.9		10.5	ns
f_{CNT}	Maximum internal global clock frequency	*(2), (4)*	126.6		95.2		MHz
t_{ACNT}	Minimum array clock period	*(2)*		7.9		10.5	ns
f_{ACNT}	Maximum internal array clock frequency	*(2), (4)*	126.6		95.2		MHz

Table 23. EPM3256A Internal Timing Parameters (Part 1 of 2) *Note (1)*							
Symbol	Parameter	Conditions	Speed Grade				Unit
			–7		–10		
			Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.9		1.2	ns
t_{IO}	I/O input pad and buffer delay			0.9		1.2	ns
t_{SEXP}	Shared expander delay			2.8		3.7	ns
t_{PEXP}	Parallel expander delay			0.5		0.6	ns
t_{LAD}	Logic array delay			2.2		2.8	ns
t_{LAC}	Logic control array delay			1.0		1.3	ns
t_{IOE}	Internal output enable delay			0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		1.2		1.6	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.7		2.1	ns
t_{OD3}	Output buffer and pad delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		6.2		6.6	ns
t_{ZX1}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		4.0		5.0	ns
t_{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		4.5		5.5	ns

Table 23. EPM3256A Internal Timing Parameters (Part 2 of 2) Note (1)							
Symbol	**Parameter**	**Conditions**	**Speed Grade**				**Unit**
			–7		**–10**		
			Min	**Max**	**Min**	**Max**	
t_{ZX3}	Output buffer enable delay, slow slew rate = on V_{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		5.0	ns
t_{SU}	Register setup time		2.1		2.9		ns
t_H	Register hold time		0.9		1.2		ns
t_{RD}	Register delay			1.2		1.6	ns
t_{COMB}	Combinatorial delay			0.8		1.2	ns
t_{IC}	Array clock delay			1.6		2.1	ns
t_{EN}	Register enable time			1.0		1.3	ns
t_{GLOB}	Global control delay			1.5		2.0	ns
t_{PRE}	Register preset time			2.3		3.0	ns
t_{CLR}	Register clear time			2.3		3.0	ns
t_{PIA}	PIA delay	*(2)*		2.4		3.2	ns
t_{LPA}	Low–power adder	*(5)*		4.0		5.0	ns

Table 24. EPM3512A External Timing Parameters Note (1)							
Symbol	**Parameter**	**Conditions**	**Speed Grade**				**Unit**
			-7		**-10**		
			Min	**Max**	**Min**	**Max**	
t_{PD1}	Input to non-registered output	C1 = 35 pF *(2)*		7.5		10.0	ns
t_{PD2}	I/O input to non-registered output	C1 = 35 pF *(2)*		7.5		10.0	ns
t_{SU}	Global clock setup time	*(2)*	5.6		7.6		ns
t_H	Global clock hold time	*(2)*	0.0		0.0		ns
t_{FSU}	Global clock setup time of fast input		3.0		3.0		ns
t_{FH}	Global clock hold time of fast input		0.0		0.0		ns
t_{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.7	1.0	6.3	ns
t_{CH}	Global clock high time		3.0		4.0		ns
t_{CL}	Global clock low time		3.0		4.0		ns
t_{ASU}	Array clock setup time	*(2)*	2.5		3.5		ns

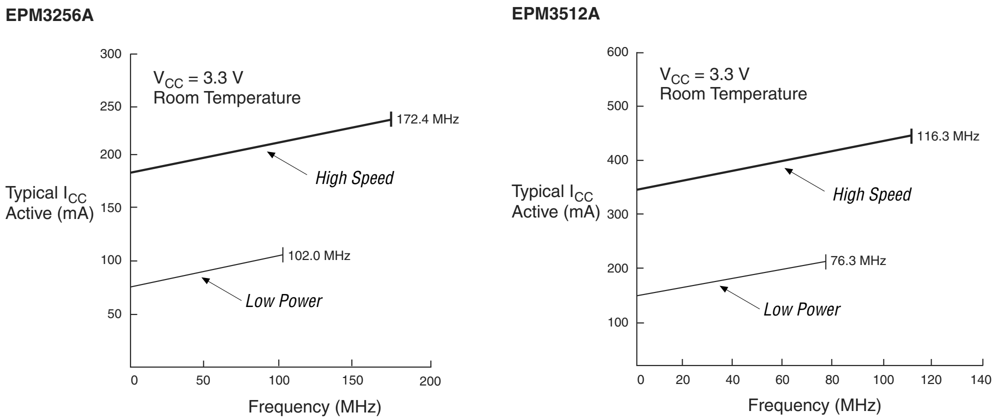
Table 24. EPM3512A External Timing Parameters *Note (1)*

Symbol	Parameter	Conditions	Speed Grade				Unit
			-7		-10		
			Min	Max	Min	Max	
t_{AH}	Array clock hold time	*(2)*	0.2		0.3		ns
t_{ACO1}	Array clock to output delay	C1 = 35 pF *(2)*	1.0	7.8	1.0	10.4	ns
t_{ACH}	Array clock high time		3.0		4.0		ns
t_{ACL}	Array clock low time		3.0		4.0		ns
t_{CPPW}	Minimum pulse width for clear and preset	*(3)*	3.0		4.0		ns
t_{CNT}	Minimum global clock period	*(2)*		8.6		11.5	ns
f_{CNT}	Maximum internal global clock frequency	*(2)*, *(4)*	116.3		87.0		MHz
t_{ACNT}	Minimum array clock period	*(2)*		8.6		11.5	ns
f_{ACNT}	Maximum internal array clock frequency	*(2)*, *(4)*	116.3		87.0		MHz

Table 25. EPM3512A Internal Timing Parameters (Part 1 of 2) *Note (1)*

Symbol	Parameter	Conditions	Speed Grade				Unit
			-7		-10		
			Min	Max	Min	Max	
t_{IN}	Input pad and buffer delay			0.7		0.9	ns
t_{IO}	I/O input pad and buffer delay			0.7		0.9	ns
t_{FIN}	Fast input delay			3.1		3.6	ns
t_{SEXP}	Shared expander delay			2.7		3.5	ns
t_{PEXP}	Parallel expander delay			0.4		0.5	ns
t_{LAD}	Logic array delay			2.2		2.8	ns
t_{LAC}	Logic control array delay			1.0		1.3	ns
t_{IOE}	Internal output enable delay			0.0		0.0	ns
t_{OD1}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 3.3 V	C1 = 35 pF		1.0		1.5	ns
t_{OD2}	Output buffer and pad delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		1.5		2.0	ns

Figure 13. I_{CC} vs. Frequency for MAX 3000A Devices



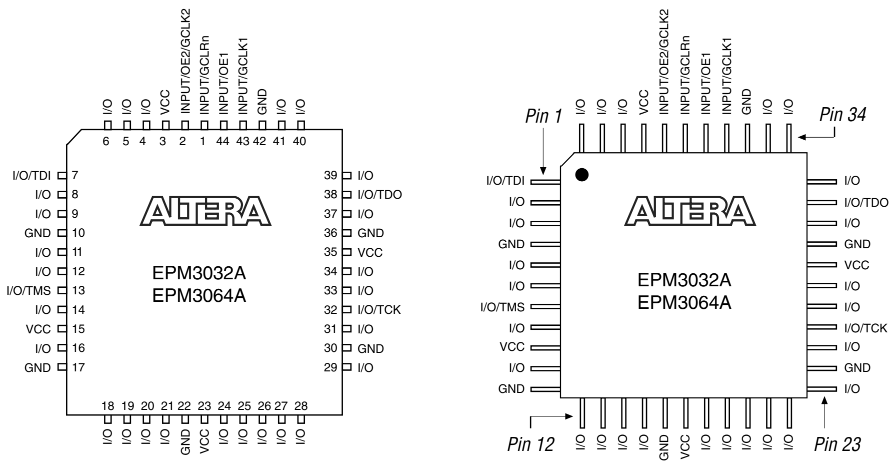
Device Pin–Outs

See the Altera web site (**http://www.altera.com**) or the *Altera Digital Library* for pin–out information.

Figures 14 through 18 show the package pin–out diagrams for MAX 3000A devices.

Figure 14. 44–Pin PLCC/TQFP Package Pin–Out Diagram

Package outlines not drawn to scale.



44-Pin PLCC

44-Pin TQFP

Figure 15. 100–Pin TQFP Package Pin–Out Diagram

Package outline not drawn to scale.

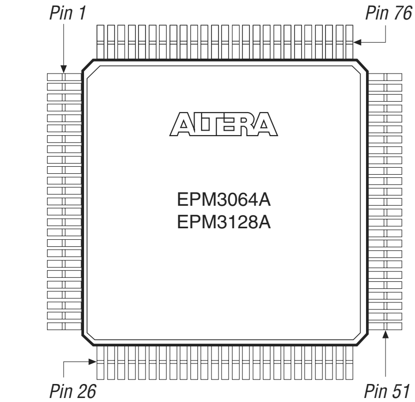


Figure 16. 144–Pin TQFP Package Pin–Out Diagram

Package outline not drawn to scale.

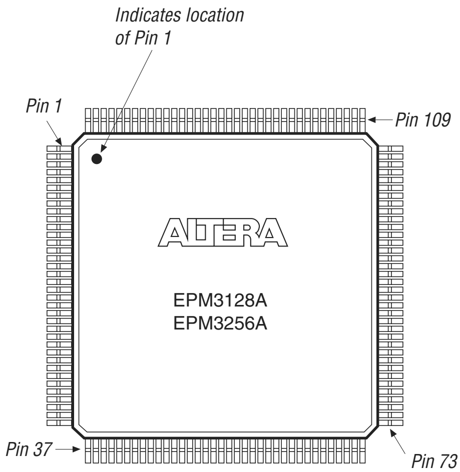


Figure 18. 256-Pin FineLine BGA Package Pin-Out Diagram

Package outline not drawn to scale.

Revision History

The information contained in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.5 supersedes information published in previous versions. The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.5:

Version 3.5

The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.5:

- New paragraph added before "Expander Product Terms".

Version 3.4

The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.4:

- Updated Table 1.